

## Description

The QH10N10 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$ , low gate charge. This device is suitable for use in Synchronous-recification application.

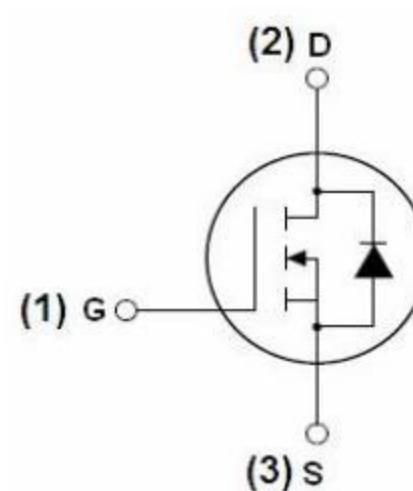
## General Features

$V_{DSS}$	$R_{DS(on)}$ @ 10V (Typ)	$R_{DS(on)}$ @ 4.5V(Typ)	$I_D$
100V	115mΩ	150mΩ	7 A

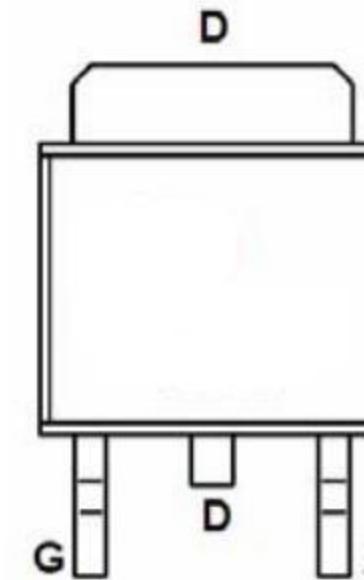
- High power and current handing capability
- Lead free product is acquired
- Surface mount package
- RoHS Compliant

**Application**

- Consumer electronic power supply
- Isolated DC/DC converter
- Motor control



Schematic Diagram



Marking and Pin Assignment



TO-252

## Ordering Information

Part Number	Marking	Case	Packaging
QH10N10	GT10N10	TO-252	2500pcs/Reel

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	7	A
Drain Current-Pulsed (Note 1)	$I_{DM}$	21	A
Maximum Power Dissipation	$P_D$	17	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	°C

## Thermal Characteristic

Thermal Resistance, Junciton-case	$R_{\theta JC}$	7.4	°C/W
Thermal Resistance,Junction-to-Ambient (Note 2)	$R_{\theta JA}$	73.5	°C/W

## Electrical Characteristics (TA=25°C unless otherwise noted)

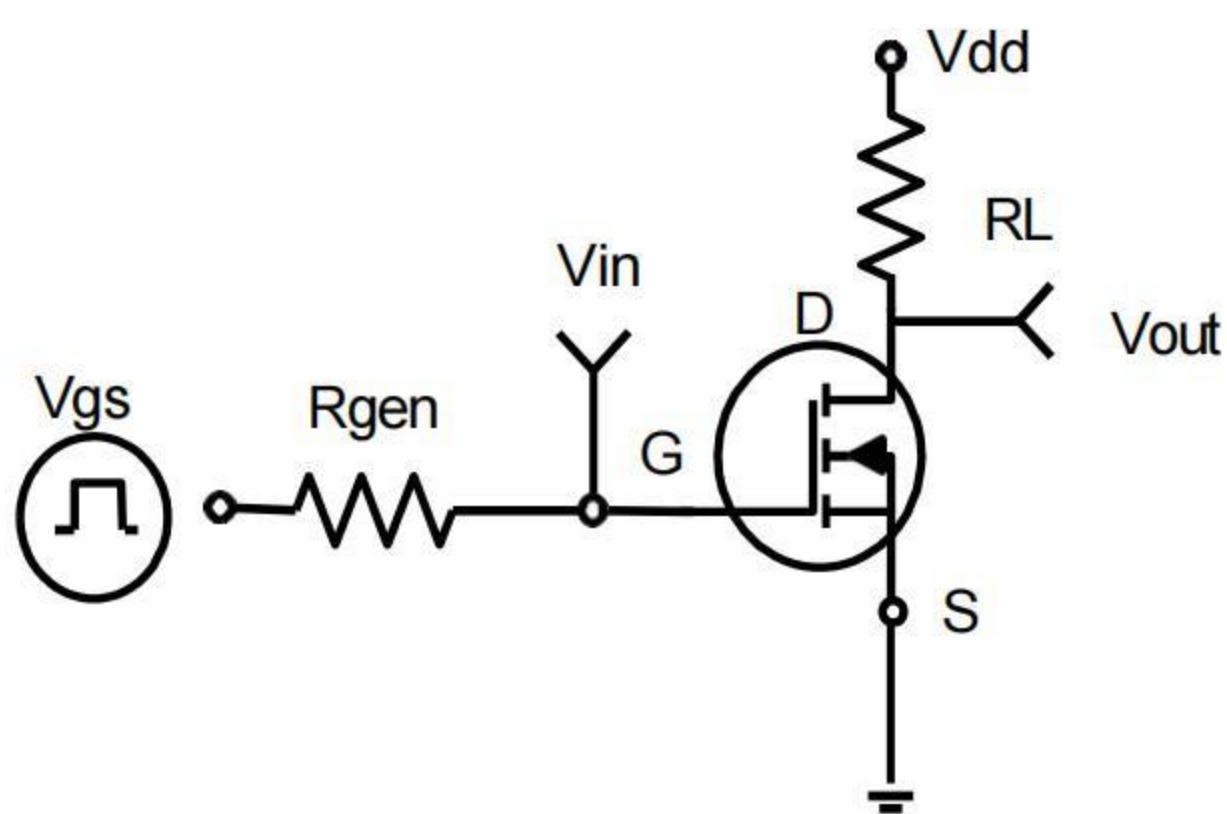
Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V I_D=250\mu A$	100	110	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=100V, V_{GS}=0V$	-	-	1	$\mu A$

Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>On Characteristics (Note 3)</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.5	2	2.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3.5A$	-	115	140	$m\Omega$
		$V_{GS}=4.5V, I_D=3.5A$	-	150	175	$m\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}=15V, I_D=2A$	3	-	-	S
<b>Dynamic Characteristics (Note 4)</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=50V, V_{GS}=0V,$ $F=1.0MHz$	-	206	-	PF
Output Capacitance	$C_{oss}$		-	28.9	-	PF
Reverse Transfer Capacitance	$C_{rss}$		-	1.4	-	PF
<b>Switching Characteristics (Note 4)</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=50V, I_D=5A$ $V_{GS}=10V, R_{GEN}=2\Omega$	-	14.7	-	nS
Turn-on Rise Time	$t_r$		-	3.5	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	20.9	-	nS
Turn-Off Fall Time	$t_f$		-	2.7	-	nS
Total Gate Charge	$Q_g$	$V_{DS}=50V, I_D=5A,$ $V_{GS}=10V$	-	4.3	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.5	-	nC
Gate-Drain Charge	$Q_{gd}$		-	1.1	-	nC
Gate plateau voltage	$V_{plateau}$			5.0		V
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}=0V, I_s=7A$	-	-	1.2	V
Diode Forward Current (Note 2)	$I_s$	$V_{GS}<V_{th}$	-	-	7	A

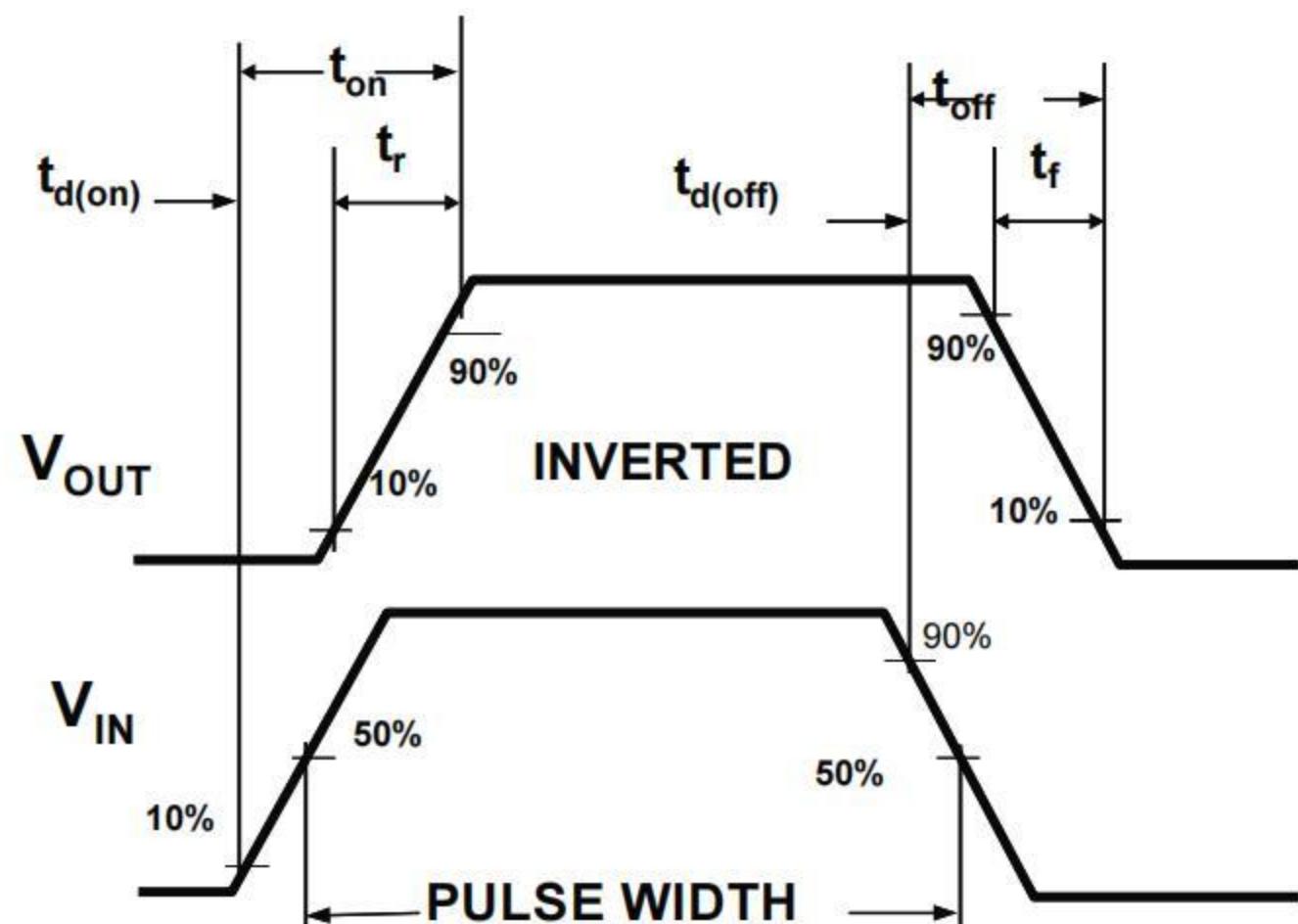
**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

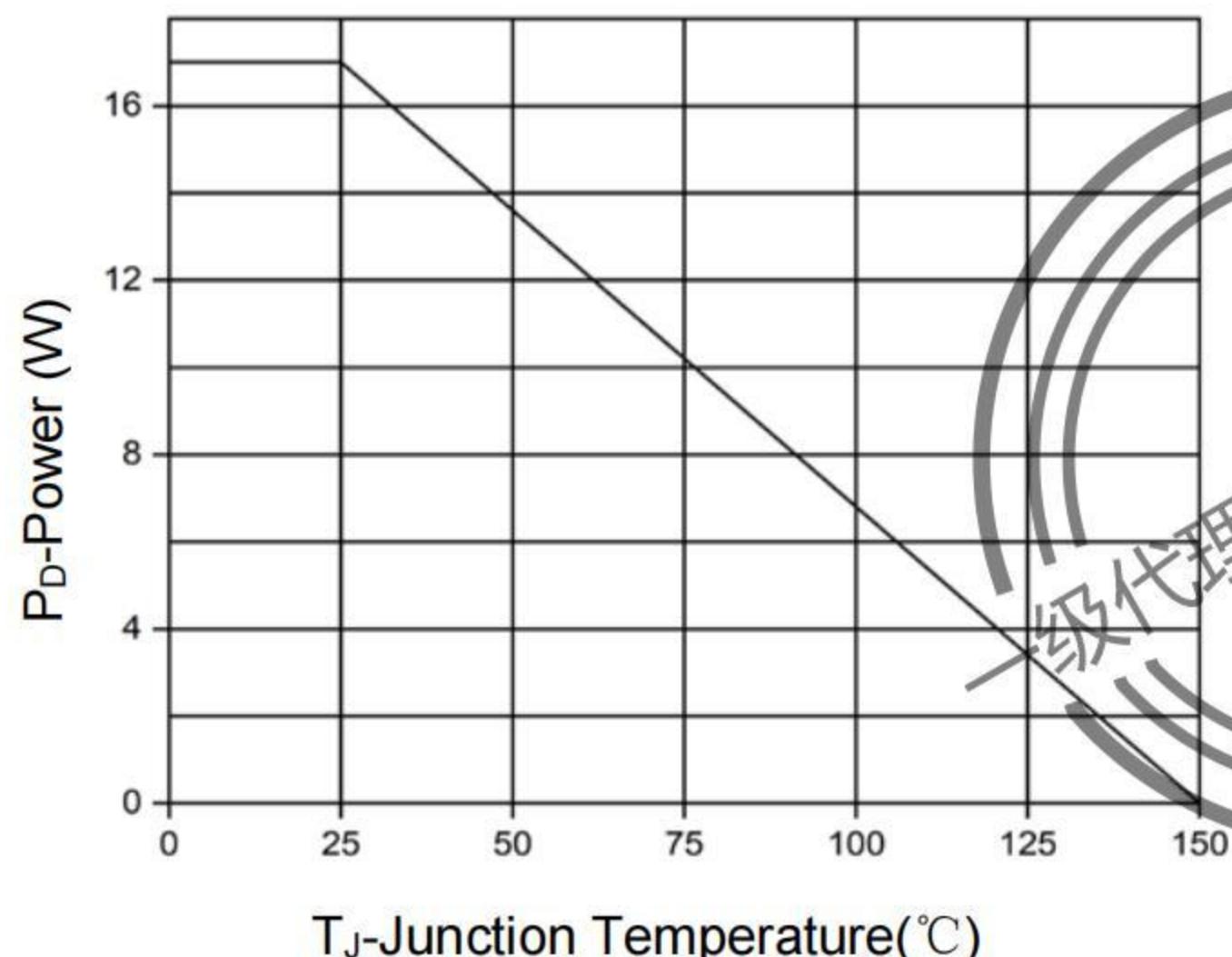
### Typical Electrical And Thermal Characteristics



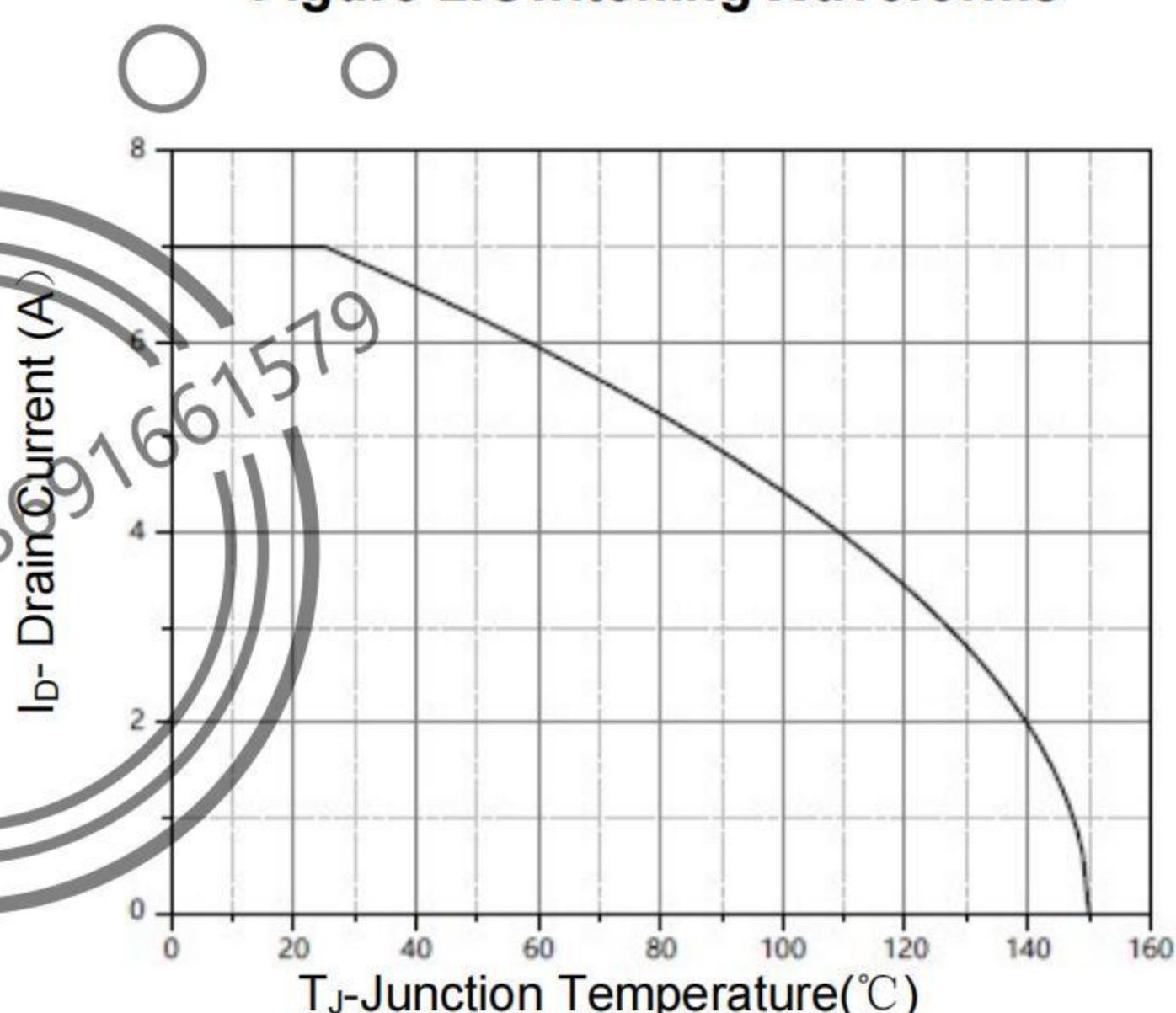
**Figure 1:Switching Test Circuit**



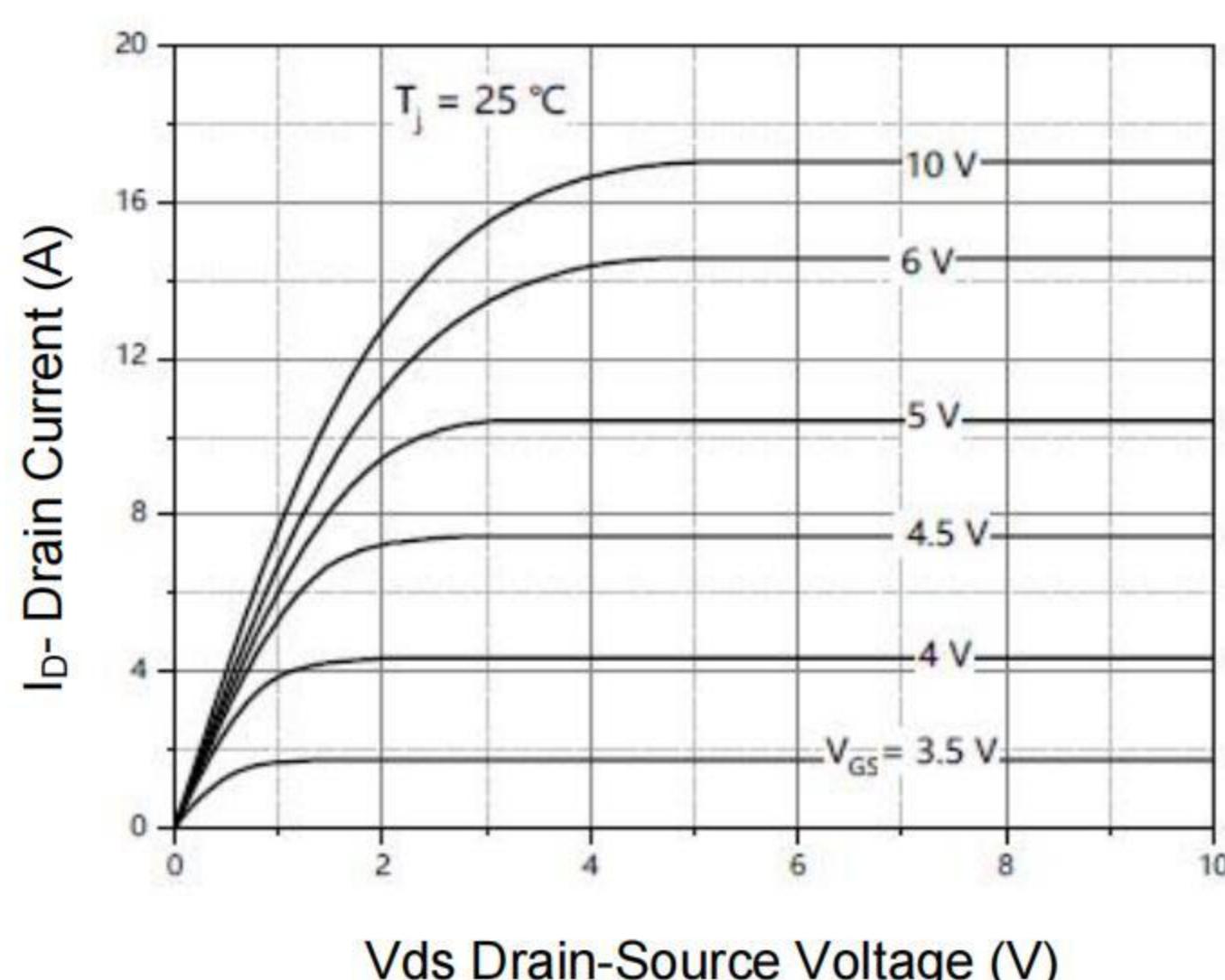
**Figure 2:Switching Waveforms**



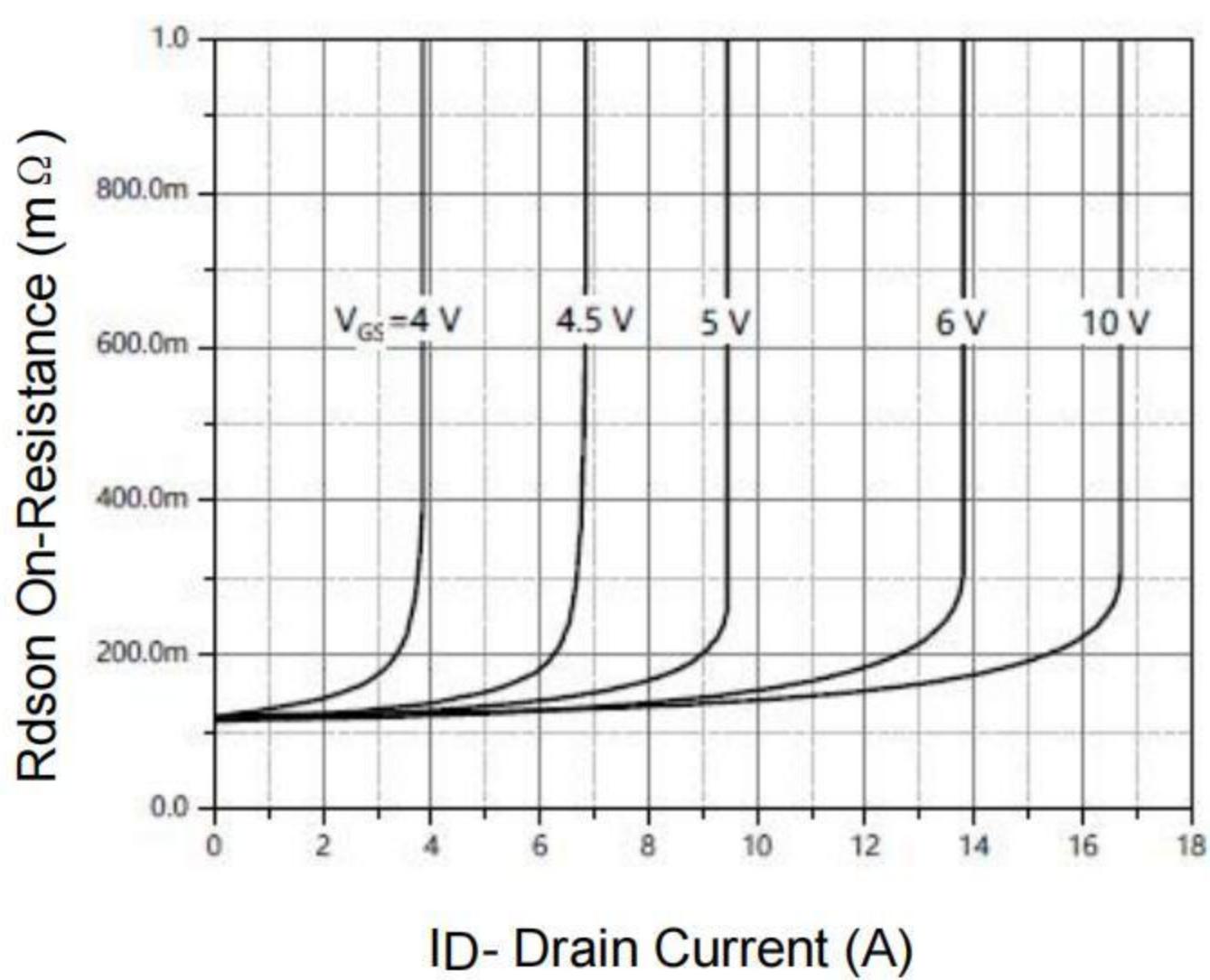
**Figure 3 Power Dissipation**



**Figure 4 Drain Current**



**Figure 5 Output characteristics**



**Figure 6 Drain-Source On-Resistance**

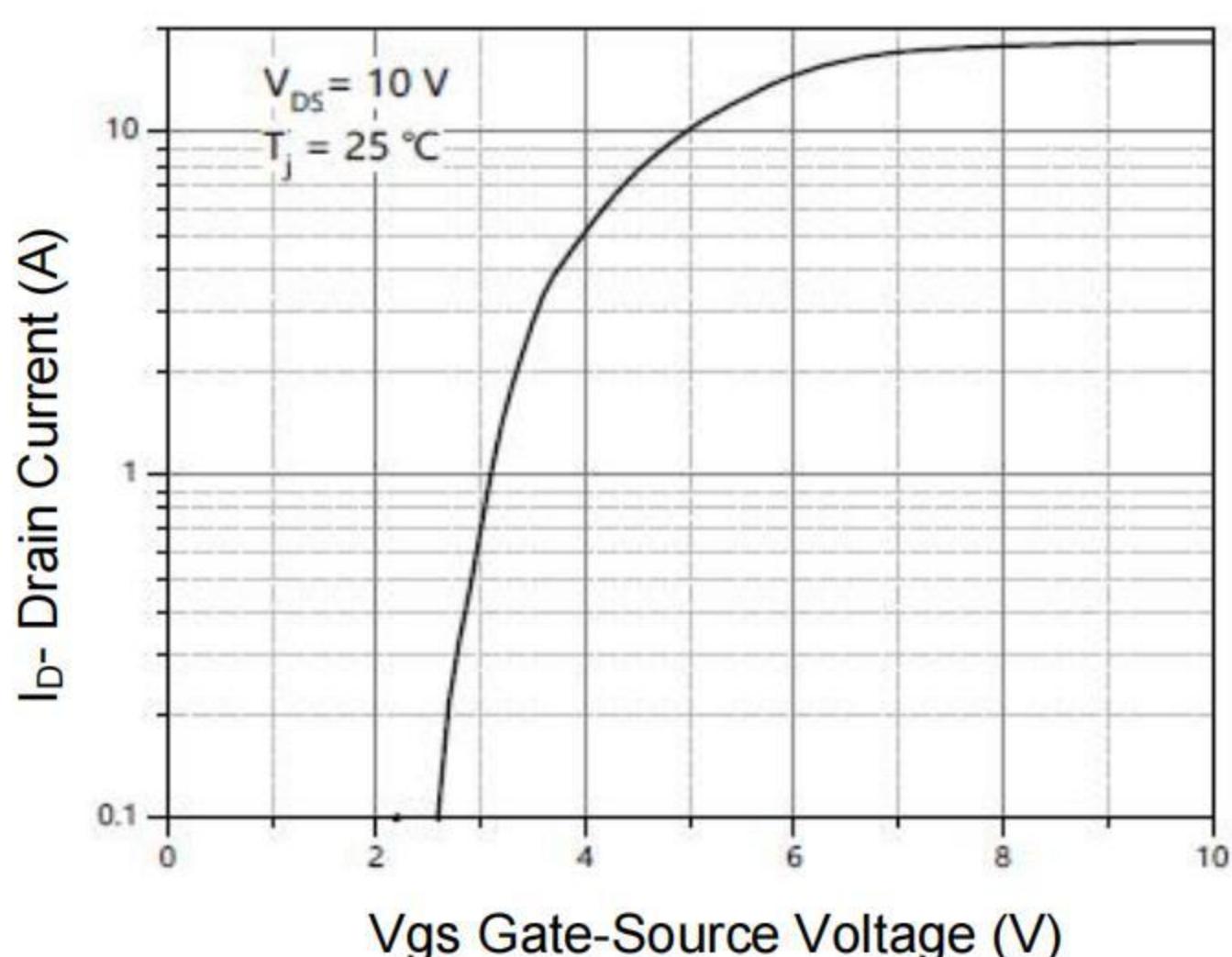


Figure 7 Transfer Characteristics

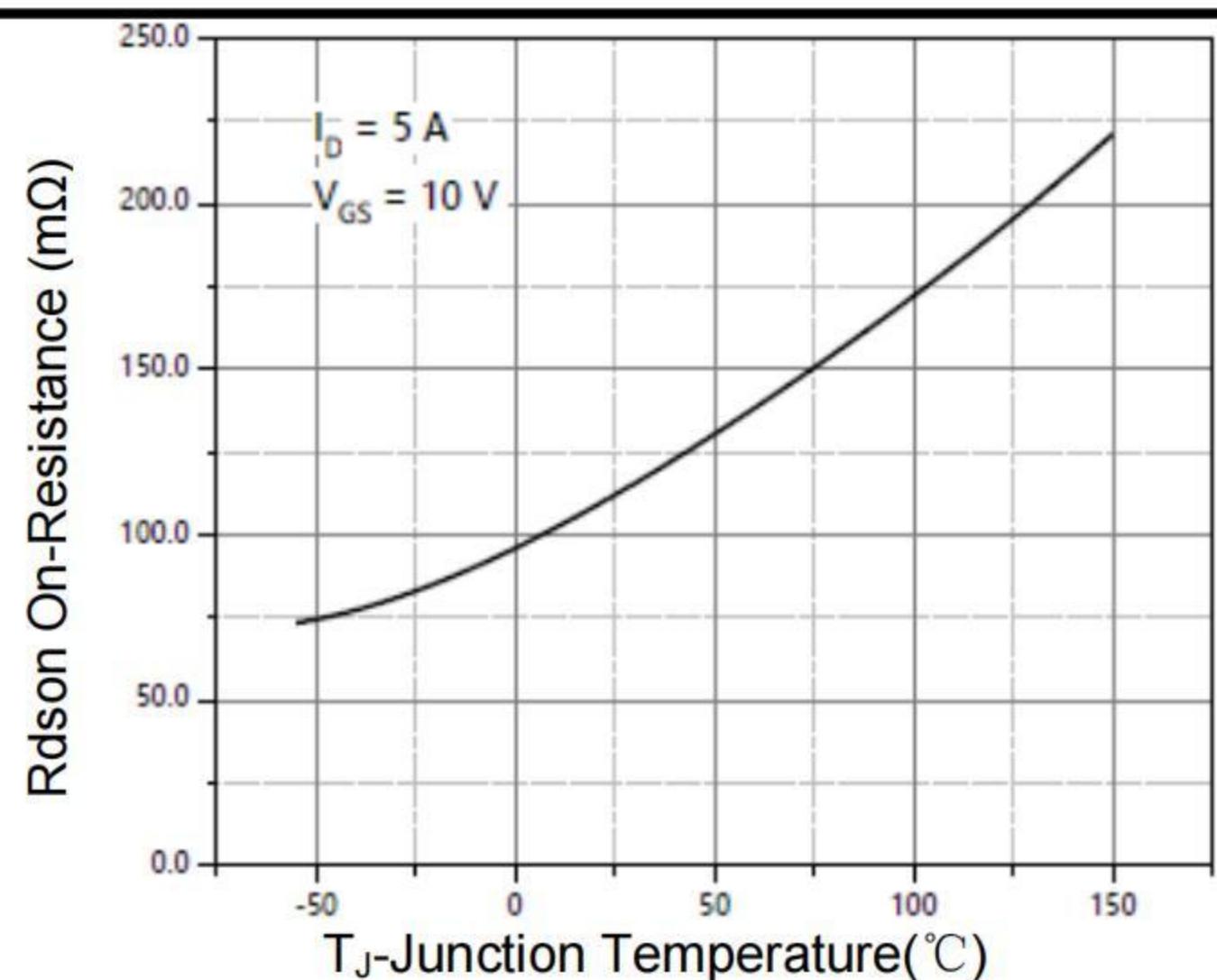


Figure 8 Drain-Source On-Resistance

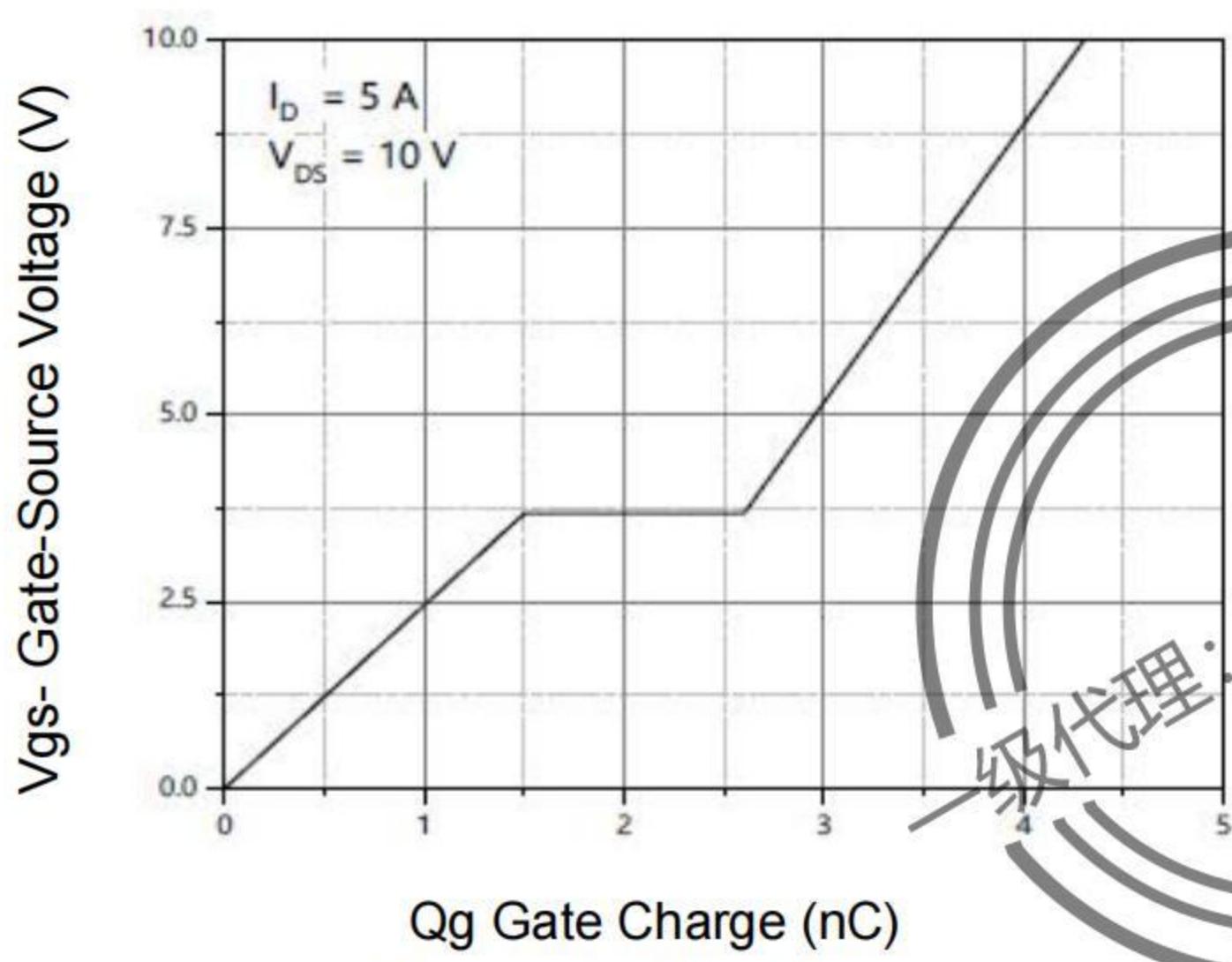


Figure 9 Gate Charge

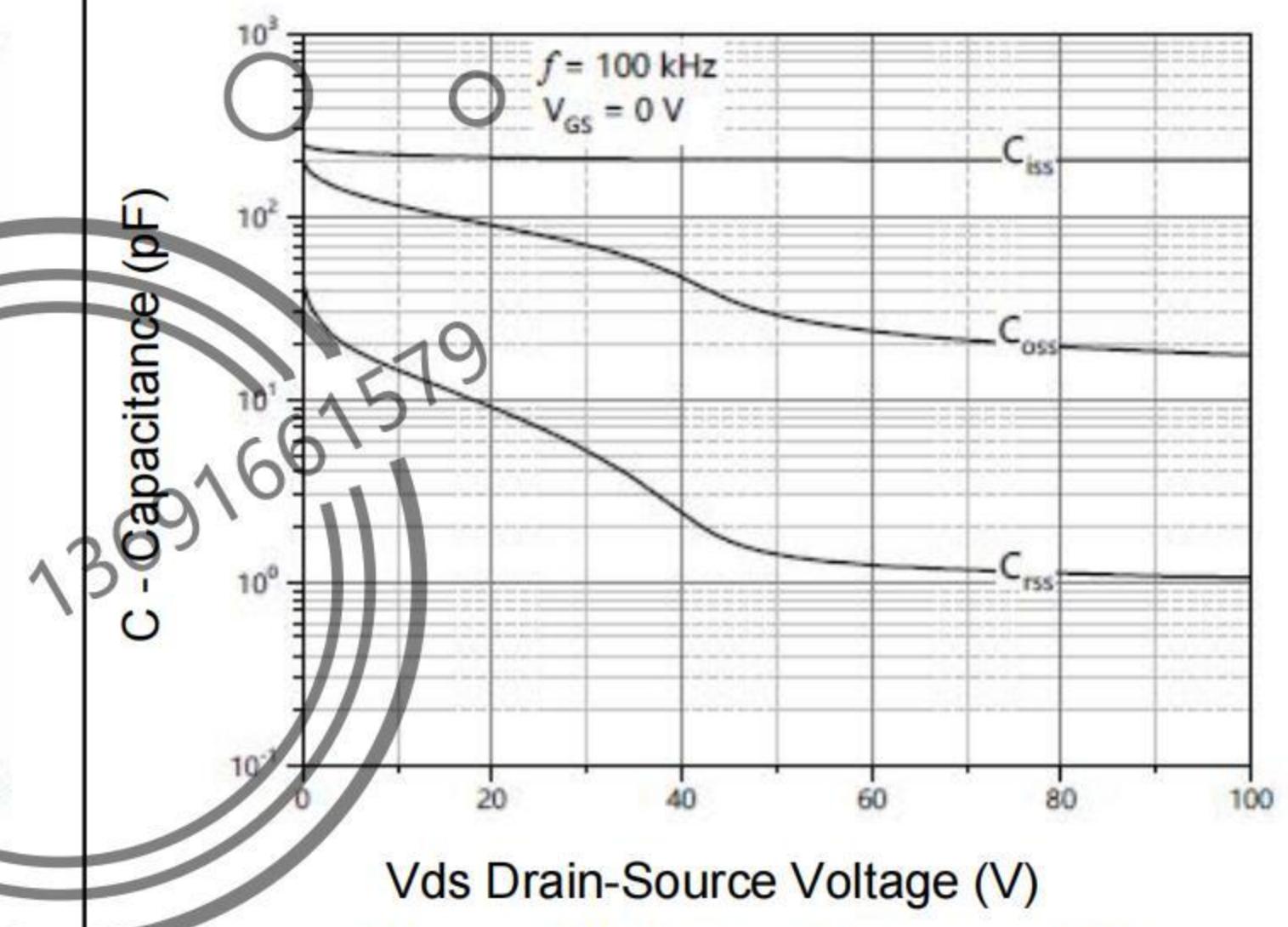


Figure 10 Capacitance vs Vds

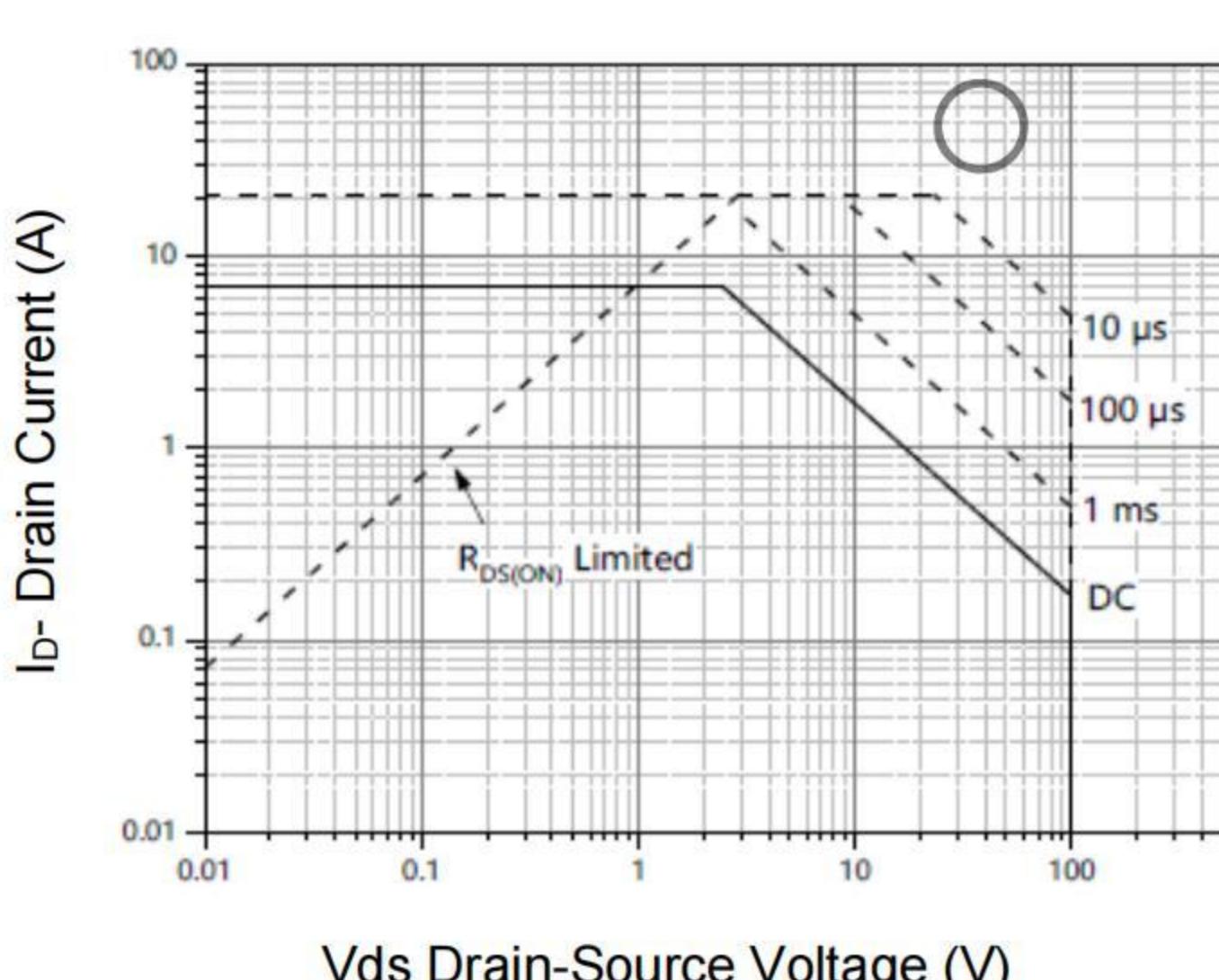


Figure 11 Safe Operation Area

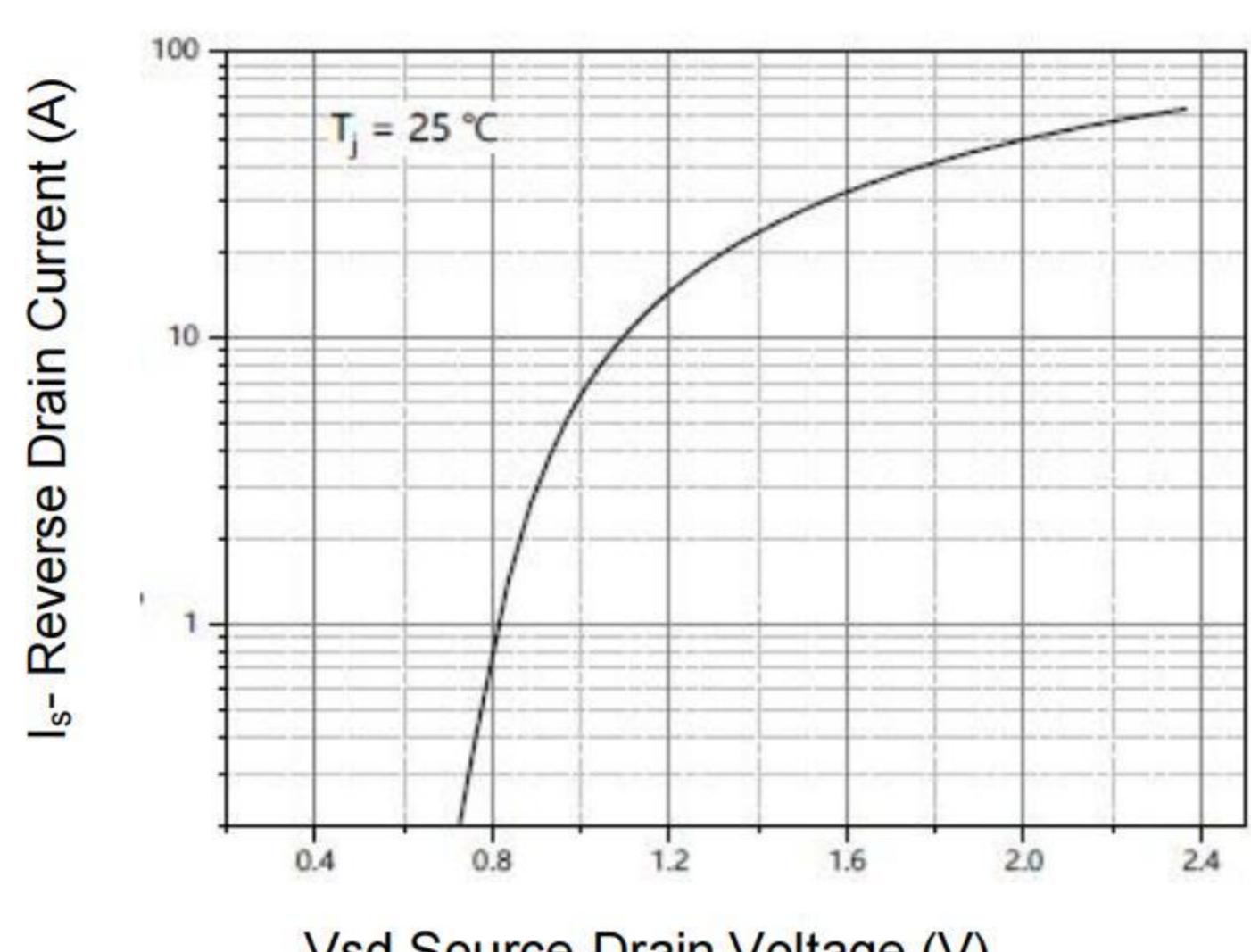
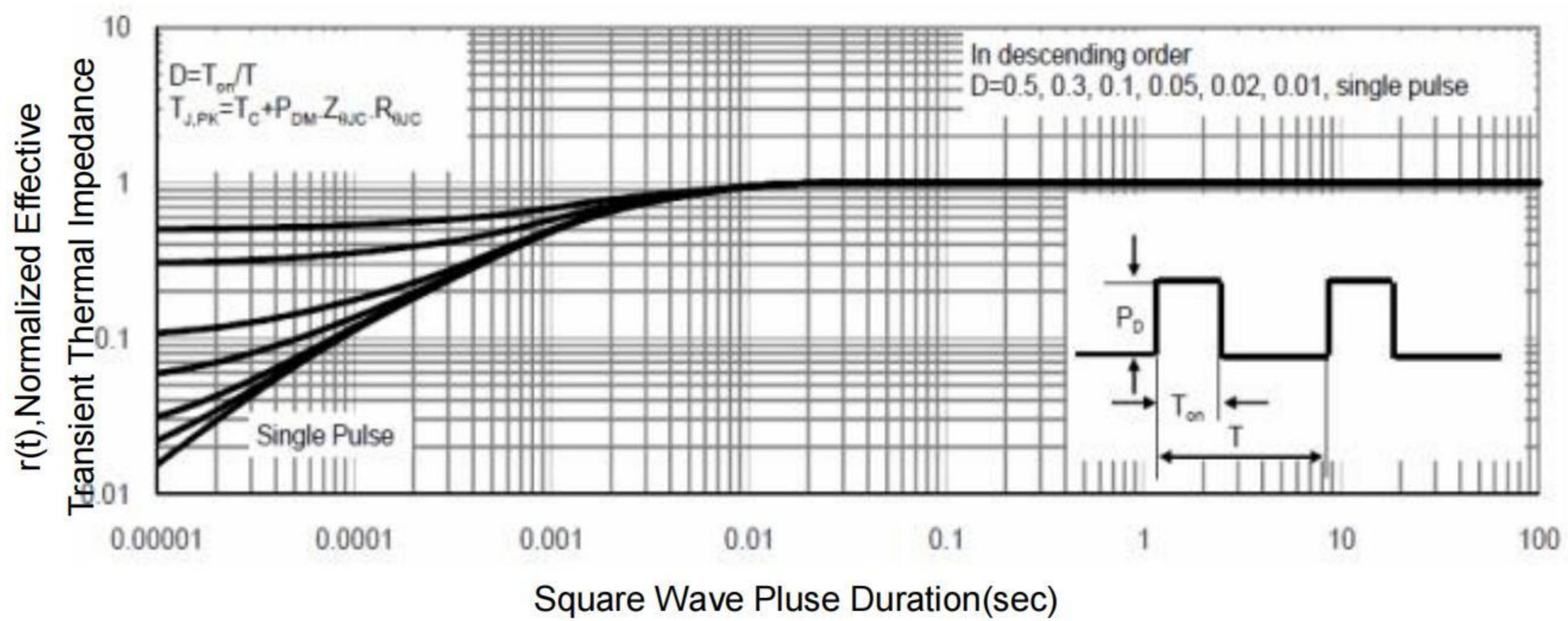


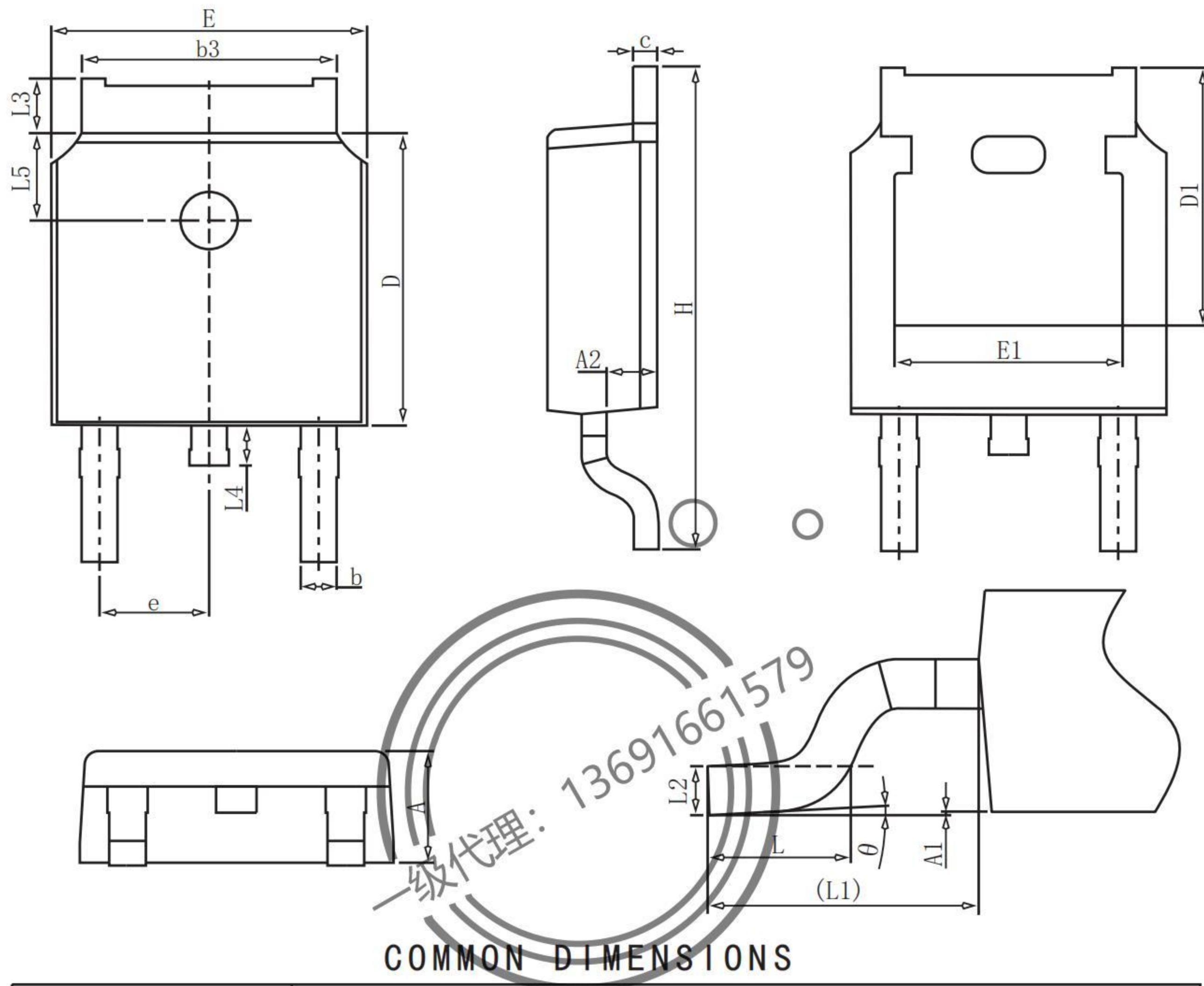
Figure 12 Source-Drain Diode Forward



**Figure 13 Normalized Maximum Transient Thermal Impedance**



### Package information



COMMON DIMENSIONS

SYMBOL	mm		
	MIN	NOM	MAX
A	2.20	2.30	2.40
A1	0.00	-	0.20
A2	0.97	1.07	1.17
b	0.68	0.78	0.90
b3	5.20	5.33	5.50
c	0.43	0.53	0.63
D	5.98	6.10	6.22
D1		5.30REF	
E	6.40	6.60	6.80
E1	4.63	-	-
e		2.286BSC	
H	9.40	10.10	10.50
L	1.38	1.50	1.75
L1		2.90REF	
L2		0.51BSC	
L3	0.88	-	1.28
L4	0.50	-	1.00
L5	1.65	1.80	1.95
θ	0°	-	8°